Extremely Slow Spin Relaxation in Cu-doped Colloidal CdSe Quantum Dots

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spins due to dangling bonds

• efficient spin relaxation

Rodina and Efros *Nano Lett.* **15**, 4214 (2015).



□ hole trapping at the Cu dopant site

□ shrinkage of carrier wave functions

□ limited interaction with the surface

□ slow spin relaxation

The left by ΔE , produces polarization \tilde{A} \Box carrier interaction with spheroidal 10^{-3} phonon modes, $E_{ph} \approx 1 \text{ meV}$, $l \approx 2$

Oron et al. Phys. Rev. Lett. **102**, 177402 (2009).

0 0.8 T 0 0.6 T 0 0.4 T 0 0.2 T 2 4 6 8 10 Temperature (K)

2nd order surface phonon spin ____ relax. rate contribution contribution Orbach process $k_{spin}(B,T) = k_{surface} + A(B) n_B(E_{ph},T) (n_B(E_{ph} + \Delta E,T) + 1)$ phonon phonon related to 🖊 emission absorption mixing of spin states

□ the combined carrier interaction with dangling bond spins at the QD surface and with phonons determine the relaxation rates

□ shrinkage of the exciton wave function limits the interaction with dangling bond spins at the surface and, hence, suppresses spin relaxation

non-expontential PL decays due to contributions
 from different ion positions (electron-hole overlaps),
 QD morphology, and the vibronic structure

□ analogous conclusions expected for other copperand silver-doped II-VI and III-V QDs

□ comparison with **CuInS**₂ **QDs** will reveal the (contested!) nature of the luminescent state in these nanostructures

Klopotowski et al. J. Phys. Chem. C 124, 1042 (2020).

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